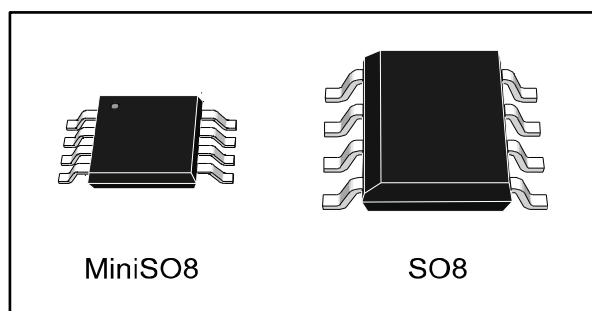


---

## Low-power, precision, rail-to-rail, 9.0 MHz, 16 V operational amplifiers

---

Datasheet - production data



### Description

The TSX7192 dual, operational amplifier (op amp) offers high precision functioning with low input offset voltage down to a maximum of 200  $\mu\text{V}$  at 25  $^{\circ}\text{C}$ . In addition, its rail-to-rail input and output functionality allows this product to be used on full range input and output without limitation. This is particularly useful for a low-voltage supply such as 2.7 V that the TSX7192 is able to operate with.

Thus, the TSX7192 has the great advantage of offering a large span of supply voltages, ranging from 2.7 V to 16 V. It can be used in multiple applications with a unique reference.

Low input bias current performance makes the TSX7192 perfect when used for signal conditioning in sensor interface applications. In addition, low-side and high-side current measurements can be easily made thanks to rail-to-rail functionality. The TSX7192 is a decompensated amplifier and must be used with a gain greater than 10 to ensure stability.

High ESD tolerance (4 kV HBM) and a wide temperature range are also good arguments to use the TSX7192 in the automotive market segment.

### Features

- Low input offset voltage: 200  $\mu\text{V}$  max.
- Rail-to-rail input and output
- Low current consumption: 850  $\mu\text{A}$  max.
- Gain bandwidth product: 9 MHz
- Low supply voltage: 2.7 to 16 V
- Stable when used with Gain  $\geq 10$
- Low input bias current: 50 pA max.
- High ESD tolerance: 4 kV HBM
- Extended temp. range: -40  $^{\circ}\text{C}$  to 125  $^{\circ}\text{C}$
- Automotive qualification

### Related products

- See the TSX7191 for single op amp version
- See the TSX712 for lower speeds with similar precision
- See the TSX562 for low-power features
- See the TSX632 for micro-power features
- See the TSX922 for higher speeds

### Applications

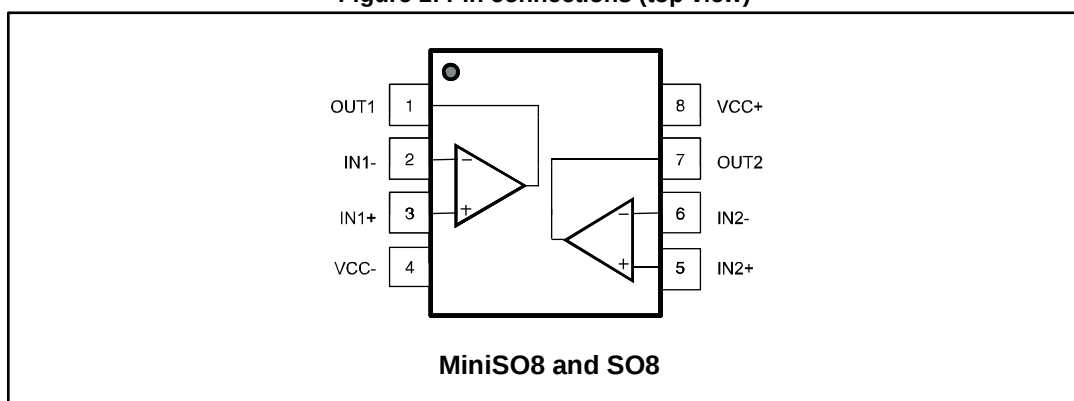
- Battery-powered instrumentation
- Instrumentation amplifier
- Active filtering
- High-impedance sensor interface
- Current sensing (high and low side)

## Contents

|          |                                                                |           |
|----------|----------------------------------------------------------------|-----------|
| <b>1</b> | <b>Package pin connections.....</b>                            | <b>3</b>  |
| <b>2</b> | <b>Absolute maximum ratings and operating conditions .....</b> | <b>4</b>  |
| <b>3</b> | <b>Electrical characteristics .....</b>                        | <b>5</b>  |
| <b>4</b> | <b>Application information .....</b>                           | <b>15</b> |
| 4.1      | Operating voltages .....                                       | 15        |
| 4.2      | Input pin voltage ranges.....                                  | 15        |
| 4.3      | Rail-to-rail input.....                                        | 15        |
| 4.4      | Rail-to-rail output.....                                       | 15        |
| 4.5      | Input offset voltage drift over temperature.....               | 16        |
| 4.6      | Long term input offset voltage drift.....                      | 16        |
| 4.7      | High values of input differential voltage.....                 | 17        |
| 4.8      | Capacitive load.....                                           | 18        |
| 4.9      | PCB layout recommendations.....                                | 19        |
| 4.10     | Optimized application recommendation .....                     | 19        |
| <b>5</b> | <b>Package information .....</b>                               | <b>20</b> |
| 5.1      | MiniSO8 package information .....                              | 21        |
| 5.2      | SO8 package information.....                                   | 22        |
| <b>6</b> | <b>Ordering information.....</b>                               | <b>23</b> |
| <b>7</b> | <b>Revision history .....</b>                                  | <b>24</b> |

# 1 Package pin connections

Figure 1: Pin connections (top view)



## 2 Absolute maximum ratings and operating conditions

Table 1: Absolute maximum ratings (AMR)

| Symbol    | Parameter                                 | Value                                  | Unit |
|-----------|-------------------------------------------|----------------------------------------|------|
| $V_{CC}$  | Supply voltage <sup>(1)</sup>             | 18                                     | V    |
| $V_{id}$  | Differential input voltage <sup>(2)</sup> | $\pm V_{CC}$                           | mV   |
| $V_{in}$  | Input voltage                             | $(V_{CC-}) - 0.2$ to $(V_{CC+}) + 0.2$ | V    |
| $I_{in}$  | Input current <sup>(3)</sup>              | 10                                     | mA   |
| $T_{stg}$ | Storage temperature                       | -65 to 150                             | °C   |
| $T_j$     | Maximum junction temperature              | 150                                    |      |
| ESD       | HBM: human body model <sup>(4)</sup>      | 4000                                   | V    |
|           | MM: machine model <sup>(5)</sup>          | 100                                    |      |
|           | CDM: charged device model <sup>(6)</sup>  | 1500                                   |      |
|           | Latch-up immunity                         | 200                                    | mA   |

**Notes:**

<sup>(1)</sup>All voltage values, except the differential voltage are with respect to the network ground terminal.

<sup>(2)</sup>Differential voltages are the non-inverting input terminal with respect to the inverting input terminal. See [Section 4.7](#) for precautions to follow when using the TSX7192 with high differential input voltage.

<sup>(3)</sup>Input current must be limited by a resistor in series with the inputs.

<sup>(4)</sup>According to JEDEC standard JESD22-A114F.

<sup>(5)</sup>According to JEDEC standard JESD22-A115A.

<sup>(6)</sup>According to ANSI/ESD STM5.3.1.

Table 2: Operating conditions

| Symbol     | Parameter                            | Value                                  | Unit |
|------------|--------------------------------------|----------------------------------------|------|
| $V_{CC}$   | Supply voltage                       | 2.7 to 16                              | V    |
| $V_{icm}$  | Common mode input voltage range      | $(V_{CC-}) - 0.1$ to $(V_{CC+}) + 0.1$ |      |
| $T_{oper}$ | Operating free air temperature range | -40 to 125                             | °C   |

### 3 Electrical characteristics

Table 3: Electrical characteristics at  $V_{CC+} = 4\text{ V}$  with  $V_{CC-} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25\text{ }^{\circ}\text{C}$ , and  $R_L > 10\text{ k}\Omega$  connected to  $V_{CC}/2$  (unless otherwise specified)

| Symbol                   | Parameter                                                         | Conditions                                                         | Min. | Typ. | Max. | Unit                                    |
|--------------------------|-------------------------------------------------------------------|--------------------------------------------------------------------|------|------|------|-----------------------------------------|
| $V_{io}$                 | Input offset voltage                                              | $T = 25\text{ }^{\circ}\text{C}$                                   |      |      | 200  | $\mu\text{V}$                           |
|                          |                                                                   | $T_{min} < T_{op} < 85\text{ }^{\circ}\text{C}$                    |      |      | 365  |                                         |
|                          |                                                                   | $T_{min} < T_{op} < 125\text{ }^{\circ}\text{C}$                   |      |      | 450  |                                         |
| $\Delta V_{io}/\Delta T$ | Input offset voltage drift <sup>(1)</sup>                         |                                                                    |      |      | 2.5  | $\mu\text{V}/^{\circ}\text{C}$          |
| $\Delta V_{io}$          | Long term input offset voltage drift <sup>(2)</sup>               | $T = 25\text{ }^{\circ}\text{C}$                                   |      | 1    |      | $\frac{\text{nV}}{\sqrt{\text{month}}}$ |
| $I_{ib}$                 | Input bias current <sup>(1)</sup>                                 | $V_{out} = V_{CC}/2$                                               |      | 1    | 50   | $\text{pA}$                             |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 200  |                                         |
| $I_{io}$                 | Input offset current <sup>(1)</sup>                               | $V_{out} = V_{CC}/2$                                               |      | 1    | 50   |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 200  |                                         |
| $R_{IN}$                 | Input resistance                                                  |                                                                    |      | 1    |      | $\text{T}\Omega$                        |
| $C_{IN}$                 | Input capacitance                                                 |                                                                    |      | 12.5 |      | $\text{pF}$                             |
| CMRR                     | Common mode rejection ratio $20\log(\Delta V_{ic}/\Delta V_{io})$ | $V_{icm} = -0.1\text{ to }4.1\text{ V}$ , $V_{out} = V_{CC}/2$     | 80   | 98   |      | $\text{dB}$                             |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       | 78   |      |      |                                         |
|                          |                                                                   | $V_{icm} = -0.1\text{ to }2\text{ V}$ , $V_{out} = V_{CC}/2$       | 91   | 103  |      |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       | 86   |      |      |                                         |
| $A_{vd}$                 | Large signal voltage gain                                         | $R_L = 2\text{ k}\Omega$ , $V_{out} = 0.3\text{ to }3.7\text{ V}$  | 110  | 136  |      |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       | 96   |      |      |                                         |
|                          |                                                                   | $R_L = 10\text{ k}\Omega$ , $V_{out} = 0.2\text{ to }3.8\text{ V}$ | 110  | 140  |      |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       | 96   |      |      |                                         |
| $V_{OH}$                 | High level output voltage (voltage drop from $V_{CC+}$ )          | $R_L = 2\text{ k}\Omega$ to $V_{CC}/2$                             |      | 28   | 50   | $\text{mV}$                             |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 60   |                                         |
|                          |                                                                   | $R_L = 10\text{ k}\Omega$ to $V_{CC}/2$                            |      | 6    | 15   |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 20   |                                         |
| $V_{OL}$                 | Low level output voltage                                          | $R_L = 2\text{ k}\Omega$ to $V_{CC}/2$                             |      | 23   | 50   |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 60   |                                         |
|                          |                                                                   | $R_L = 10\text{ k}\Omega$ to $V_{CC}/2$                            |      | 5    | 15   |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 20   |                                         |
| $I_{out}$                | $I_{sink}$                                                        | $V_{out} = V_{CC}$                                                 | 25   | 37   |      | $\text{mA}$                             |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       | 15   |      |      |                                         |
|                          | $I_{source}$                                                      | $V_{out} = 0\text{ V}$                                             | 35   | 45   |      |                                         |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       | 20   |      |      |                                         |
| $I_{CC}$                 | Supply current per amplifier                                      | No load, $V_{out} = V_{CC}/2$                                      |      | 570  | 800  | $\mu\text{A}$                           |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                       |      |      | 900  |                                         |

## Electrical characteristics

TSX7192

| Symbol   | Parameter                         | Conditions                                                                                                  | Min. | Typ.  | Max. | Unit                   |
|----------|-----------------------------------|-------------------------------------------------------------------------------------------------------------|------|-------|------|------------------------|
| GBP      | Gain bandwidth product            | $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$                                                           | 5    | 7.7   |      | MHz                    |
| $\phi_m$ | Phase margin                      | Gain = 10, $R_L = 10\text{ k}\Omega$ ,<br>$C_L = 100\text{ pF}$                                             |      | 42    |      | Degrees                |
| SRn      | Negative slew rate                | $A_v = 10$ , $V_{out} = 3\text{ V}_{PP}$ ,<br>10 % to 90 %                                                  | 1.3  | 2.3   |      | V/ $\mu$ s             |
|          |                                   | $T_{min} < T_{op} < T_{max}$                                                                                | 1.0  |       |      |                        |
| SRp      | Positive slew rate                | $A_v = 10$ , $V_{out} = 3\text{ V}_{PP}$ ,<br>10 % to 90 %                                                  | 1.5  | 2.5   |      |                        |
|          |                                   | $T_{min} < T_{op} < T_{max}$                                                                                | 1.1  |       |      |                        |
| $e_n$    | Equivalent input noise voltage    | $f = 1\text{ kHz}$                                                                                          |      | 22    |      | $\frac{nV}{\sqrt{Hz}}$ |
|          |                                   | $f = 10\text{ kHz}$                                                                                         |      | 19    |      |                        |
| THD+N    | Total harmonic distortion + noise | $f = 1\text{ kHz}$ , $A_v = 10$ , $R_L = 10\text{ k}\Omega$ ,<br>$BW = 22\text{ kHz}$ , $V_{out} = 3V_{PP}$ |      | 0.003 |      | %                      |

## Notes:

<sup>(1)</sup>Maximum values are guaranteed by design.

<sup>(2)</sup>Typical value is based on the  $V_{io}$  drift observed after 1000h at 125 °C extrapolated to 25 °C using the Arrhenius law and assuming an activation energy of 0.7 eV. The operational amplifier is aged in follower mode configuration (see [Section 4.6](#)).

**Table 4: Electrical characteristics at  $V_{CC+} = 10\text{ V}$  with  $V_{CC-} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25\text{ }^{\circ}\text{C}$ , and  $R_L > 10\text{ k}\Omega$  connected to  $V_{CC}/2$  (unless otherwise specified)**

| Symbol                   | Parameter                                                         | Conditions                                                        | Min. | Typ. | Max. | Unit                             |
|--------------------------|-------------------------------------------------------------------|-------------------------------------------------------------------|------|------|------|----------------------------------|
| $V_{io}$                 | Input offset voltage                                              | $T = 25\text{ }^{\circ}\text{C}$                                  |      |      | 200  | $\mu\text{V}$                    |
|                          |                                                                   | $T_{min} < T_{op} < 85\text{ }^{\circ}\text{C}$                   |      |      | 365  |                                  |
|                          |                                                                   | $T_{min} < T_{op} < 125\text{ }^{\circ}\text{C}$                  |      |      | 450  |                                  |
| $\Delta V_{io}/\Delta T$ | Input offset voltage drift <sup>(1)</sup>                         |                                                                   |      |      | 2.5  | $\mu\text{V}/^{\circ}\text{C}$   |
| $\Delta V_{io}$          | Long term input offset voltage drift <sup>(2)</sup>               | $T = 25\text{ }^{\circ}\text{C}$                                  |      | 25   |      | $\frac{nV}{\sqrt{\text{month}}}$ |
| $I_{ib}$                 | Input bias current <sup>(1)</sup>                                 | $V_{out} = V_{CC}/2$                                              |      | 1    | 50   | pA                               |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                      |      |      | 200  |                                  |
| $I_{io}$                 | Input offset current <sup>(1)</sup>                               | $V_{out} = V_{CC}/2$                                              |      | 1    | 50   |                                  |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                      |      |      | 200  |                                  |
| $R_{IN}$                 | Input resistance                                                  |                                                                   |      | 1    |      | T $\Omega$                       |
| $C_{IN}$                 | Input capacitance                                                 |                                                                   |      | 12.5 |      | pF                               |
| CMRR                     | Common mode rejection ratio $20\log(\Delta V_{ic}/\Delta V_{io})$ | $V_{icm} = -0.1\text{ to }10.1\text{ V}$ , $V_{out} = V_{CC}/2$   | 88   | 100  |      | dB                               |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                      | 84   |      |      |                                  |
|                          |                                                                   | $V_{icm} = -0.1\text{ to }8\text{ V}$ , $V_{out} = V_{CC}/2$      | 98   | 106  |      |                                  |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                      | 92   |      |      |                                  |
| $A_{vd}$                 | Large signal voltage gain                                         | $R_L = 2\text{ k}\Omega$ , $V_{out} = 0.3\text{ to }9.7\text{ V}$ | 110  | 140  |      |                                  |
|                          |                                                                   | $T_{min} < T_{op} < T_{max}$                                      | 100  |      |      |                                  |

| Symbol    | Parameter                                                   | Conditions                                                                                                          | Min. | Typ.   | Max. | Unit                                 |
|-----------|-------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------|------|--------|------|--------------------------------------|
| $A_{vd}$  | Large signal voltage gain                                   | $R_L = 10\text{ k}\Omega$ , $V_{out} = 0.2\text{ to }9.8\text{ V}$                                                  | 110  |        |      | dB                                   |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        | 100  |        |      |                                      |
| $V_{OH}$  | High level output voltage<br>(voltage drop from $V_{CC+}$ ) | $R_L = 2\text{ k}\Omega$ to $V_{CC}/2$                                                                              |      | 45     | 70   | mV                                   |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        |      |        | 80   |                                      |
|           |                                                             | $R_L = 10\text{ k}\Omega$ to $V_{CC}/2$                                                                             |      | 10     | 30   |                                      |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        |      |        | 40   |                                      |
| $V_{OL}$  | Low level output voltage                                    | $R_L = 2\text{ k}\Omega$ to $V_{CC}/2$                                                                              |      | 42     | 70   |                                      |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        |      |        | 80   |                                      |
|           |                                                             | $R_L = 10\text{ k}\Omega$ to $V_{CC}/2$                                                                             |      | 9      | 30   |                                      |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        |      |        | 40   |                                      |
| $I_{out}$ | $I_{sink}$                                                  | $V_{out} = V_{CC}$                                                                                                  | 30   | 39     |      | mA                                   |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        | 15   |        |      |                                      |
|           | $I_{source}$                                                | $V_{out} = 0\text{ V}$                                                                                              | 50   | 69     |      |                                      |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        | 40   |        |      |                                      |
| $I_{CC}$  | Supply current per amplifier                                | No load, $V_{out} = V_{CC}/2$                                                                                       |      | 630    | 850  | $\mu\text{A}$                        |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        |      |        | 1000 |                                      |
| GBP       | Gain bandwidth product                                      | $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$                                                                   | 5    | 9      |      | MHz                                  |
| $\phi_m$  | Phase margin                                                | $G = 10$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$                                                        |      | 48     |      | Degrees                              |
| SRn       | Negative slew rate                                          | $A_v = 10$ , $V_{out} = 8\text{ V}_{PP}$ ,<br>10 % to 90 %                                                          | 1.3  | 2.3    |      | V/ $\mu\text{s}$                     |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        | 1.0  |        |      |                                      |
| SRp       | Positive slew rate                                          | $A_v = 10$ , $V_{out} = 8\text{ V}_{PP}$ ,<br>10 % to 90 %                                                          | 1.5  | 2.5    |      |                                      |
|           |                                                             | $T_{min} < T_{op} < T_{max}$                                                                                        | 1.1  |        |      |                                      |
| $e_n$     | Equivalent input noise<br>voltage                           | $f = 1\text{ kHz}$                                                                                                  |      | 22     |      | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ |
|           |                                                             | $f = 10\text{ kHz}$                                                                                                 |      | 19     |      |                                      |
| THD+N     | Total harmonic distortion +<br>noise                        | $f = 1\text{ kHz}$ , $A_v = 10$ , $R_L = 10\text{ k}\Omega$ ,<br>$BW = 22\text{ kHz}$ , $V_{out} = 9\text{ V}_{PP}$ |      | 0.0001 |      | %                                    |

**Notes:**

<sup>(1)</sup>Maximum values are guaranteed by design.

<sup>(2)</sup>Typical value is based on the  $V_{io}$  drift observed after 1000h at 125 °C extrapolated to 25 °C using the Arrhenius law and assuming an activation energy of 0.7 eV. The operational amplifier is aged in follower mode configuration (see [Section 4.6](#)).

Table 5: Electrical characteristics at  $V_{CC+} = 16\text{ V}$  with  $V_{CC-} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25\text{ }^{\circ}\text{C}$ , and  $R_L > 10\text{ k}\Omega$  connected to  $V_{CC}/2$  (unless otherwise specified)

| Symbol                   | Parameter                                                            | Conditions                                                          | Min. | Typ. | Max. | Unit                                    |
|--------------------------|----------------------------------------------------------------------|---------------------------------------------------------------------|------|------|------|-----------------------------------------|
| $V_{io}$                 | Input offset voltage                                                 | $T = 25\text{ }^{\circ}\text{C}$                                    |      |      | 200  | $\mu\text{V}$                           |
|                          |                                                                      | $T_{min} < T_{op} < 85\text{ }^{\circ}\text{C}$                     |      |      | 365  |                                         |
|                          |                                                                      | $T_{min} < T_{op} < 125\text{ }^{\circ}\text{C}$                    |      |      | 450  |                                         |
| $\Delta V_{io}/\Delta T$ | Input offset voltage drift <sup>(1)</sup>                            |                                                                     |      |      | 2.5  | $\mu\text{V}/^{\circ}\text{C}$          |
| $\Delta V_{io}$          | Long term input offset voltage drift <sup>(2)</sup>                  | $T = 25\text{ }^{\circ}\text{C}$                                    |      | 500  |      | $\frac{\text{nV}}{\sqrt{\text{month}}}$ |
| $I_{ib}$                 | Input bias current <sup>(1)</sup>                                    | $V_{out} = V_{CC}/2$                                                |      | 1    | 50   | $\text{pA}$                             |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 200  |                                         |
| $I_{io}$                 | Input offset current <sup>(1)</sup>                                  | $V_{out} = V_{CC}/2$                                                |      | 1    | 50   |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 200  |                                         |
| $R_{IN}$                 | Input resistance                                                     |                                                                     |      | 1    |      | $\text{T}\Omega$                        |
| $C_{IN}$                 | Input capacitance                                                    |                                                                     |      | 12.5 |      | $\text{pF}$                             |
| CMRR                     | Common mode rejection ratio $20\log(\Delta V_{icm}/\Delta V_{io})$   | $V_{icm} = -0.1\text{ to }16.1\text{ V}$ , $V_{out} = V_{CC}/2$     | 94   | 107  |      | $\text{dB}$                             |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 90   |      |      |                                         |
|                          |                                                                      | $V_{icm} = -0.1\text{ to }14\text{ V}$ , $V_{out} = V_{CC}/2$       | 100  | 107  |      |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 90   |      |      |                                         |
| SVRR                     | Supply voltage rejection ratio $20\log(\Delta V_{cc}/\Delta V_{io})$ | $V_{cc} = 4\text{ to }16\text{ V}$                                  | 100  | 131  |      |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 90   |      |      |                                         |
| $A_{vd}$                 | Large signal voltage gain                                            | $R_L = 2\text{ k}\Omega$ , $V_{out} = 0.3\text{ to }15.7\text{ V}$  | 110  | 146  |      |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 100  |      |      |                                         |
|                          |                                                                      | $R_L = 10\text{ k}\Omega$ , $V_{out} = 0.2\text{ to }15.8\text{ V}$ | 110  | 149  |      |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 100  |      |      |                                         |
| $V_{OH}$                 | High level output voltage (voltage drop from $V_{CC+}$ )             | $R_L = 2\text{ k}\Omega$                                            |      | 100  | 130  | $\text{mV}$                             |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 150  |                                         |
|                          |                                                                      | $R_L = 10\text{ k}\Omega$                                           |      | 16   | 40   |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 50   |                                         |
| $V_{OL}$                 | Low level output voltage                                             | $R_L = 2\text{ k}\Omega$                                            |      | 70   | 130  |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 150  |                                         |
|                          |                                                                      | $R_L = 10\text{ k}\Omega$                                           |      | 15   | 40   |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 50   |                                         |
| $I_{out}$                | $I_{sink}$                                                           | $V_{out} = V_{CC}$                                                  | 30   | 40   |      | $\text{mA}$                             |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 15   |      |      |                                         |
|                          | $I_{source}$                                                         | $V_{out} = 0\text{ V}$                                              | 50   | 68   |      |                                         |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        | 45   |      |      |                                         |
| $I_{CC}$                 | Supply current per amplifier                                         | No load, $V_{out} = V_{CC}/2$                                       |      | 660  | 900  | $\mu\text{A}$                           |
|                          |                                                                      | $T_{min} < T_{op} < T_{max}$                                        |      |      | 1000 |                                         |

| Symbol   | Parameter                         | Conditions                                                                                                           | Min. | Typ.   | Max. | Unit                   |
|----------|-----------------------------------|----------------------------------------------------------------------------------------------------------------------|------|--------|------|------------------------|
| GBP      | Gain bandwidth product            | $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$                                                                    | 5    | 8.5    |      | MHz                    |
| $\phi_m$ | Phase margin                      | $G = 10$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$                                                         |      | 51     |      | Degrees                |
| SRn      | Negative slew rate                | $A_v = 10$ , $V_{out} = 10\text{ V}_{PP}$ ,<br>10 % to 90 %                                                          | 1.5  | 2.4    |      | V/ $\mu$ s             |
|          |                                   | $T_{min} < T_{op} < T_{max}$                                                                                         | 1.1  |        |      |                        |
| SRp      | Positive slew rate                | $A_v = 10$ , $V_{out} = 10\text{ V}_{PP}$ ,<br>10 % to 90 %                                                          | 1.5  | 2.5    |      |                        |
|          |                                   | $T_{min} < T_{op} < T_{max}$                                                                                         | 1.1  |        |      |                        |
| $e_n$    | Equivalent input noise voltage    | $f = 1\text{ kHz}$                                                                                                   |      | 22     |      | $\frac{nV}{\sqrt{Hz}}$ |
|          |                                   | $f = 10\text{ kHz}$                                                                                                  |      | 19     |      |                        |
| THD+N    | Total harmonic distortion + Noise | $f = 1\text{ kHz}$ , $A_v = 10$ , $R_L = 10\text{ k}\Omega$ ,<br>$BW = 22\text{ kHz}$ , $V_{out} = 10\text{ V}_{PP}$ |      | 0.0001 |      | %                      |

**Notes:**

<sup>(1)</sup>Maximum values are guaranteed by design.

<sup>(2)</sup>Typical value is based on the  $V_{io}$  drift observed after 1000h at 125 °C extrapolated to 25 °C using the Arrhenius law and assuming an activation energy of 0.7 eV. The operational amplifier is aged in follower mode configuration (see [Section 4.6](#)).

Figure 2: Supply current vs. supply voltage

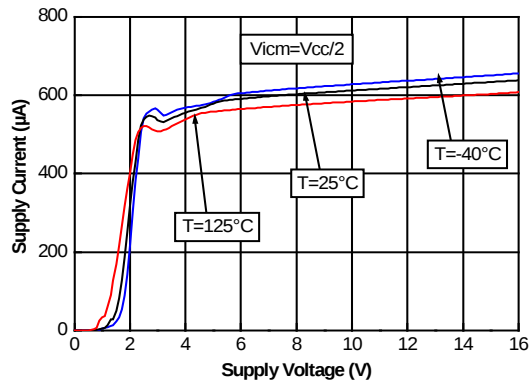


Figure 3: Input offset voltage distribution at VCC = 16 V

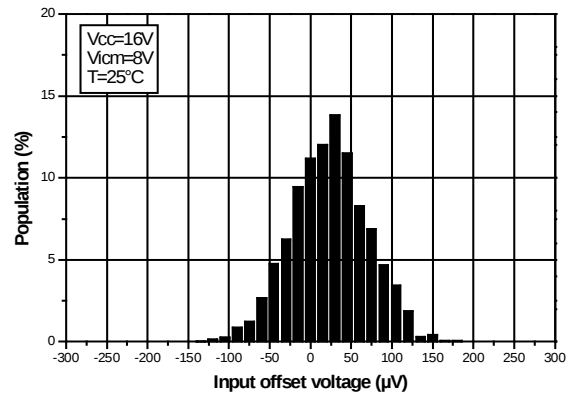


Figure 4: Input offset voltage distribution at VCC = 4 V

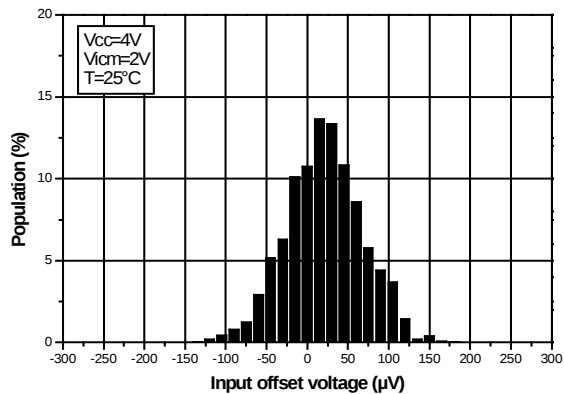


Figure 5: Input offset voltage vs. temperature at VCC = 16 V

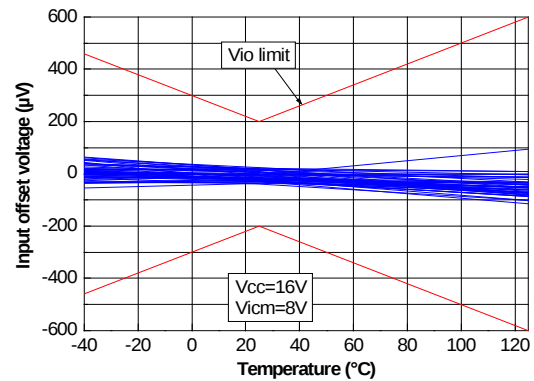


Figure 6: Input offset voltage drift population

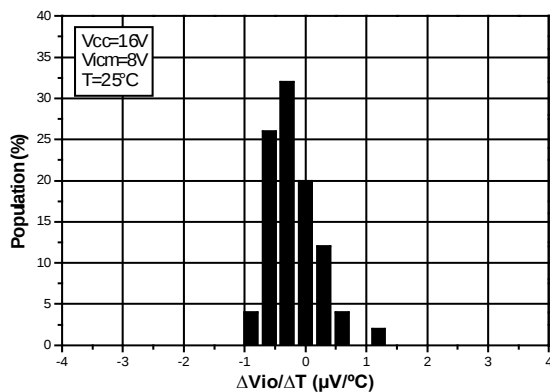


Figure 7: Input offset voltage vs. supply voltage at VICM = 0 V

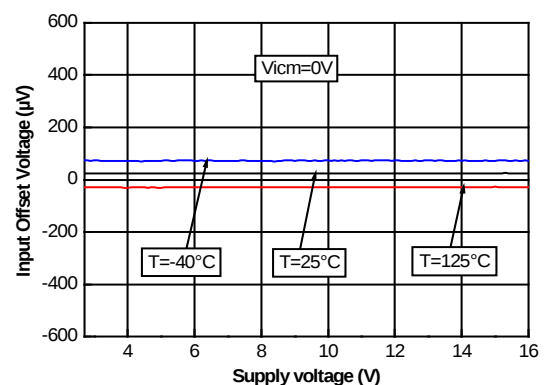


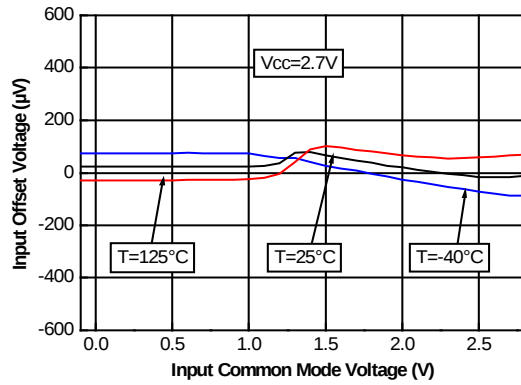
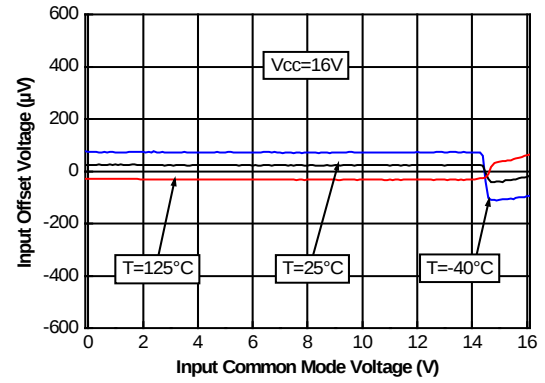
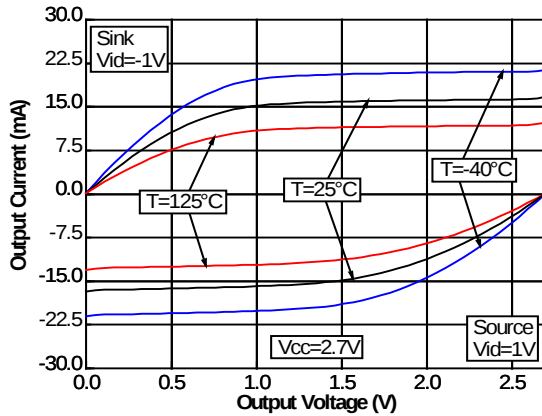
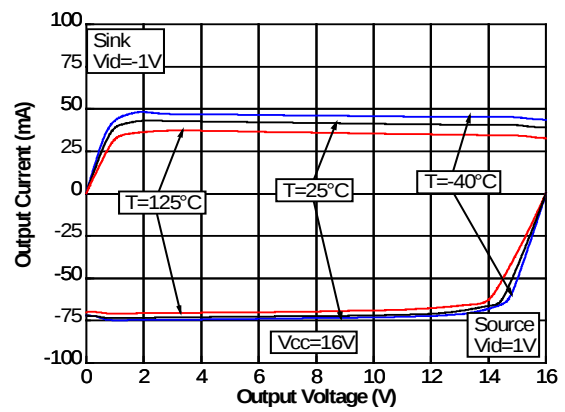
Figure 8: Input offset voltage vs. common mode voltage at  $V_{CC} = 2.7\text{ V}$ Figure 9: Input offset voltage vs. common mode voltage at  $V_{CC} = 16\text{ V}$ Figure 10: Output current vs. output voltage at  $V_{CC} = 2.7\text{ V}$ Figure 11: Output current vs. output voltage at  $V_{CC} = 16\text{ V}$ 

Figure 12: Output low voltage vs. supply voltage

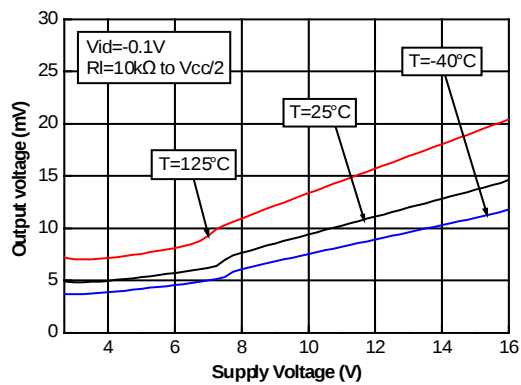
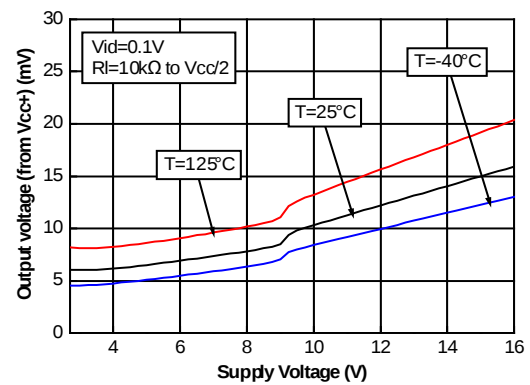
Figure 13: Output high voltage (drop from  $V_{CC+}$ ) vs. supply voltage

Figure 14: Output voltage vs. input voltage close to the rail at VCC = 16 V

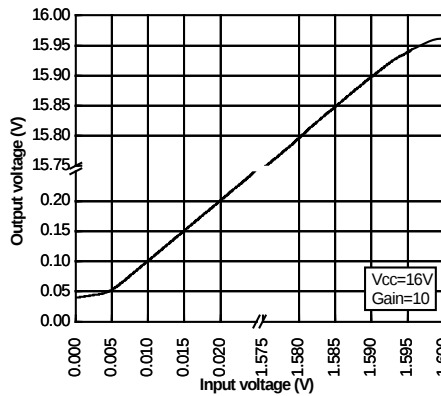


Figure 15: Slew rate vs. supply voltage

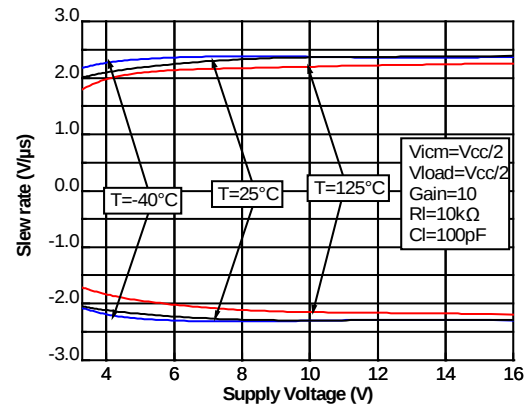


Figure 16: Negative slew rate at VCC = 16 V

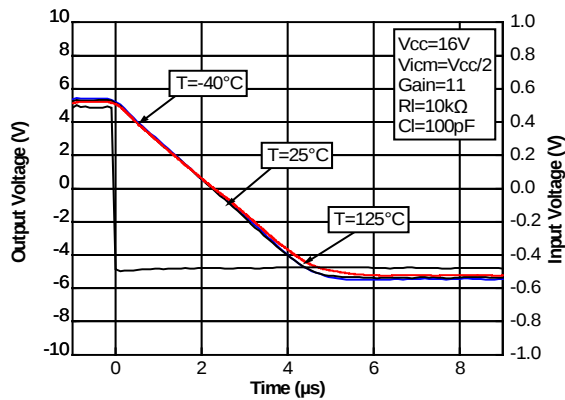


Figure 17: Positive slew rate at VCC = 16 V

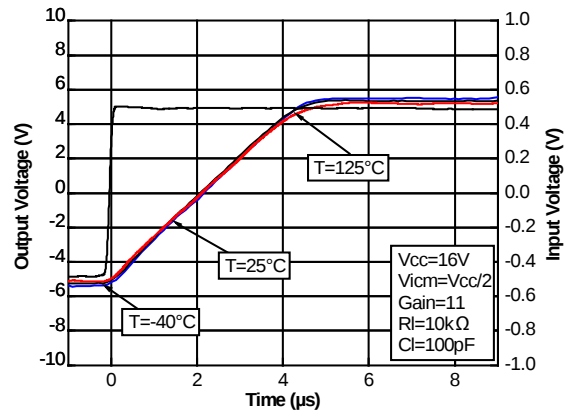


Figure 18: Response to a small input voltage step

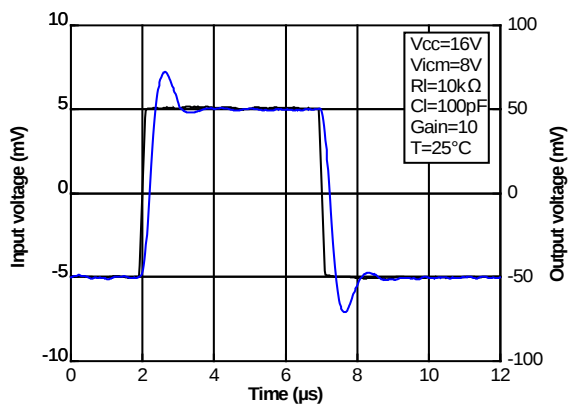


Figure 19: Recovery behavior after a negative step on the input

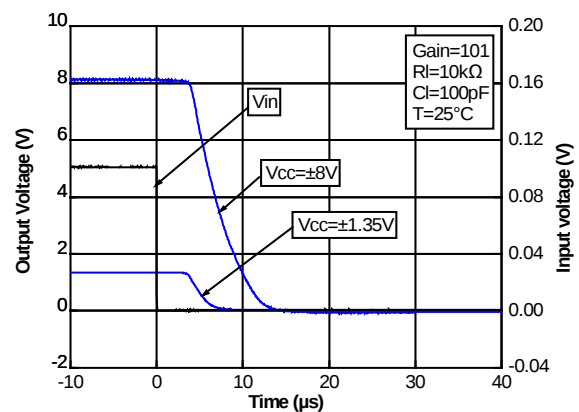


Figure 20: Recovery behavior after a positive step on the input

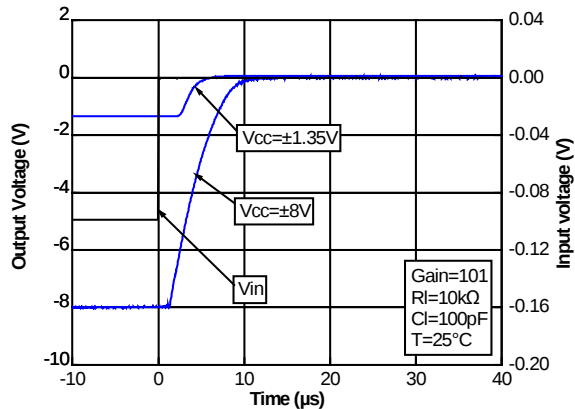
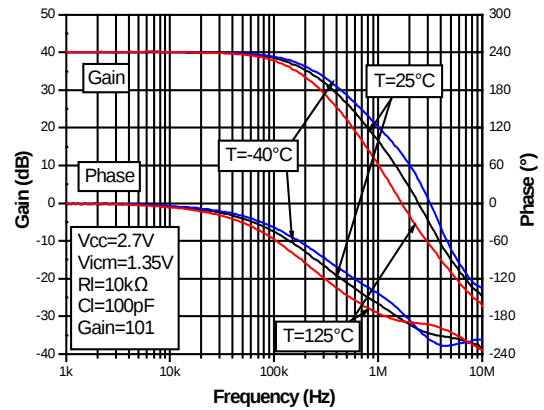
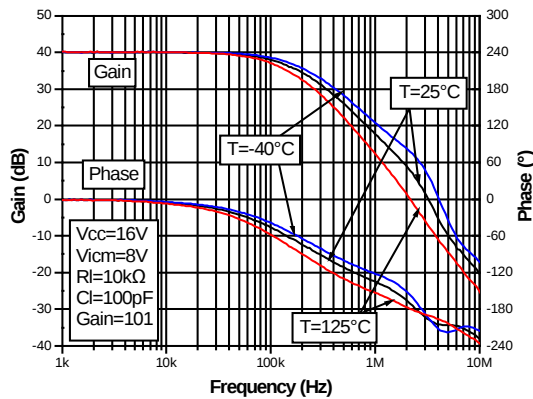
Figure 21: Bode diagram at  $V_{CC} = 2.7V$ Figure 22: Bode diagram at  $V_{CC} = 16V$ 

Figure 23: Power supply rejection ratio (PSRR) vs. frequency

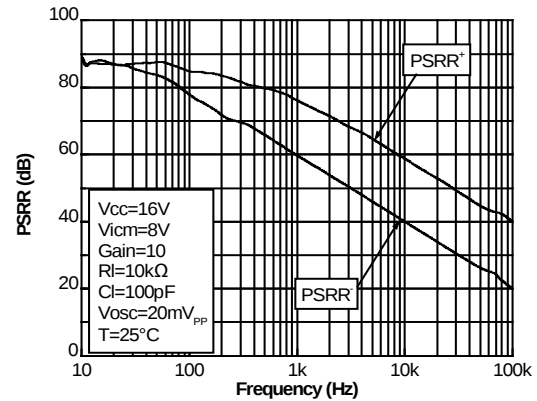


Figure 24: Output overshoot vs. capacitive load

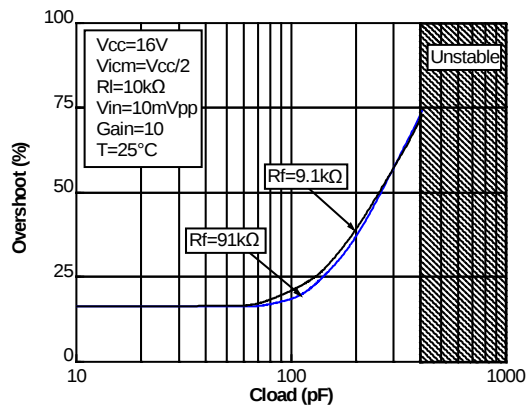


Figure 25: Output impedance vs. frequency in closed loop configuration

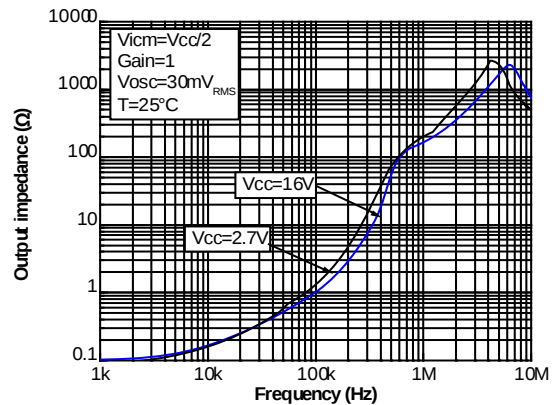


Figure 26: THD + N vs. frequency

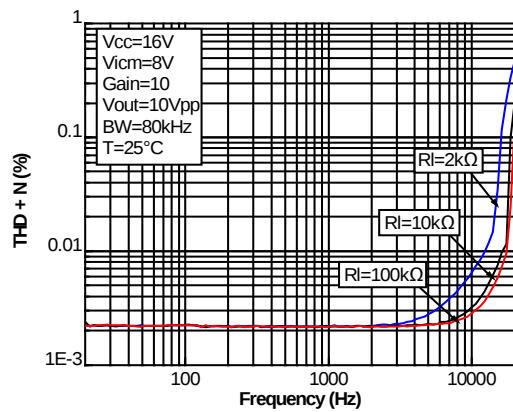


Figure 27: THD + N vs. output voltage

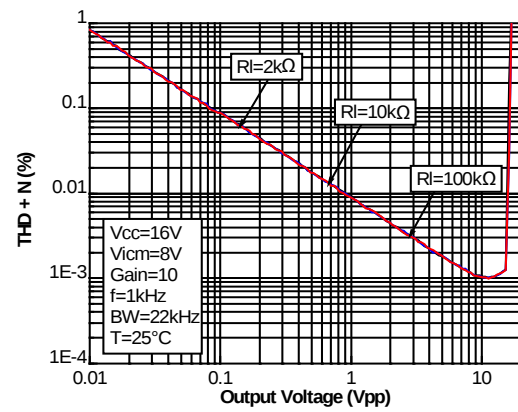


Figure 28: Noise vs. frequency

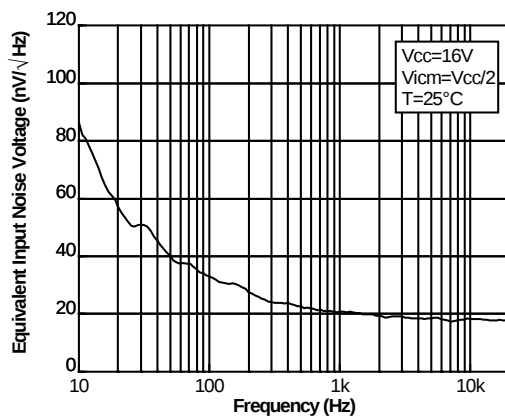
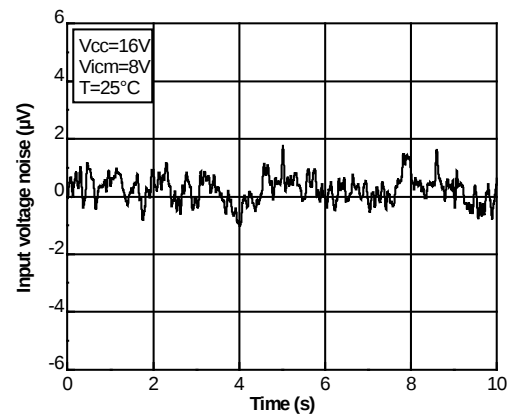


Figure 29: 0.1 to 10Hz noise



## 4 Application information

### 4.1 Operating voltages

The TSX7192 device can operate from 2.7 to 16 V. The parameters are fully specified for 4 V, 10 V, and 16 V power supplies. However, the parameters are very stable in the full  $V_{CC}$  range. Additionally, the main specifications are guaranteed in extended temperature ranges from -40 to +125 °C.

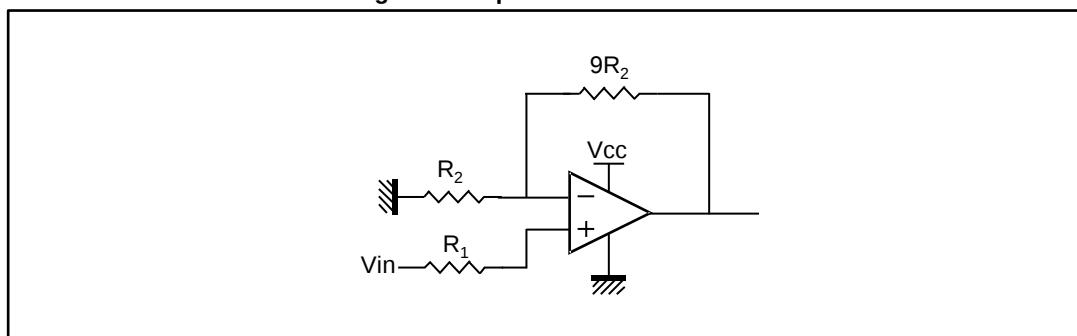
### 4.2 Input pin voltage ranges

The TSX7192 device has internal ESD diode protection on the inputs. These diodes are connected between the input and each supply rail to protect the input MOSFETs from electrical discharge.

If the input pin voltage exceeds the power supply by 0.5 V, the ESD diodes become conductive and excessive current can flow through them. Without limitation this over current can damage the device.

In this case, it is important to limit the current to 10 mA, by adding resistance on the input pin, as described in [Figure 30](#).

Figure 30: Input current limitation



### 4.3 Rail-to-rail input

The TSX7192 device has a rail-to-rail input, and the input common mode range is extended from  $V_{CC-} - 0.1$  V to  $V_{CC+} + 0.1$  V.

### 4.4 Rail-to-rail output

The operational amplifier output levels can go close to the rails: to a maximum of 40 mV above and below the rail when connected to a 10 k $\Omega$  resistive load to  $V_{CC}/2$ .

## 4.5 Input offset voltage drift over temperature

The maximum input voltage drift variation over temperature is defined as the offset variation related to the offset value measured at 25 °C. The operational amplifier is one of the main circuits of the signal conditioning chain, and the amplifier input offset is a major contributor to the chain accuracy. The signal chain accuracy at 25 °C can be compensated during production at application level. The maximum input voltage drift over temperature enables the system designer to anticipate the effect of temperature variations.

The maximum input voltage drift over temperature is computed using [Equation 1](#).

**Equation 1**

$$\frac{\Delta V_{io}}{\Delta T} = \max \left| \frac{V_{io}(T) - V_{io}(25\text{ °C})}{T - 25\text{ °C}} \right|$$

Where T = -40 °C and 125 °C.

The TSX7192 datasheet maximum value is guaranteed by measurements on a representative sample size ensuring a C<sub>pk</sub> (process capability index) greater than 1.3.

## 4.6 Long term input offset voltage drift

To evaluate product reliability, two types of stress acceleration are used:

- Voltage acceleration, by changing the applied voltage
- Temperature acceleration, by changing the die temperature (below the maximum junction temperature allowed by the technology) with the ambient temperature.

The voltage acceleration has been defined based on JEDEC results, and is defined using [Equation 2](#).

**Equation 2**

$$A_{FV} = e^{\beta \cdot (V_S - V_U)}$$

Where:

A<sub>FV</sub> is the voltage acceleration factor

β is the voltage acceleration constant in 1/V, constant technology parameter (β = 1)

V<sub>S</sub> is the stress voltage used for the accelerated test

V<sub>U</sub> is the voltage used for the application

The temperature acceleration is driven by the Arrhenius model, and is defined in [Equation 3](#).

**Equation 3**

$$A_{FT} = e^{\frac{E_a}{k} \cdot \left( \frac{1}{T_U} - \frac{1}{T_S} \right)}$$

Where:

A<sub>FT</sub> is the temperature acceleration factor

E<sub>a</sub> is the activation energy of the technology based on the failure rate

$k$  is the Boltzmann constant ( $8.6173 \times 10^{-5} \text{ eV.K}^{-1}$ )

$T_U$  is the temperature of the die when  $V_U$  is used (K)

$T_S$  is the temperature of the die under temperature stress (K)

The final acceleration factor,  $A_F$ , is the multiplication of the voltage acceleration factor and the temperature acceleration factor ([Equation 4](#)).

#### Equation 4

$$A_F = A_{FT} \times A_{FV}$$

$A_F$  is calculated using the temperature and voltage defined in the mission profile of the product. The  $A_F$  value can then be used in [Equation 5](#) to calculate the number of months of use equivalent to 1000 hours of reliable stress duration.

#### Equation 5

$$\text{Months} = A_F \times 1000 \text{ h} \times 12 \text{ months} / (24 \text{ h} \times 365.25 \text{ days})$$

To evaluate the op amp reliability, a follower stress condition is used where  $V_{CC}$  is defined as a function of the maximum operating voltage and the absolute maximum rating (as recommended by JEDEC rules).

The  $V_{io}$  drift (in  $\mu\text{V}$ ) of the product after 1000 h of stress is tracked with parameters at different measurement conditions (see [Equation 6](#)).

#### Equation 6

$$V_{CC} = \max V_{op} \text{ with } V_{icm} = V_{CC} / 2$$

The long term drift parameter ( $\Delta V_{io}$ ), estimating the reliability performance of the product, is obtained using the ratio of the  $V_{io}$  (input offset voltage value) drift over the square root of the calculated number of months ([Equation 7](#)).

#### Equation 7

$$\Delta V_{io} = \frac{V_{io} \text{ drift}}{\sqrt{(\text{months})}}$$

Where  $V_{io}$  drift is the measured drift value in the specified test conditions after 1000 h stress duration.

## 4.7 High values of input differential voltage

In a closed loop configuration, which represents the typical use of an op amp, the input differential voltage is low (close to  $V_{io}$ ). However, some specific conditions can lead to higher input differential values, such as:

- operation in an output saturation state
- operation at speeds higher than the device bandwidth, with output voltage dynamics limited by slew rate.
- use of the amplifier in a comparator configuration, hence in open loop

Use of the TSX7191 in comparator configuration, especially combined with high temperature and long duration can create a permanent drift of  $V_{io}$ .

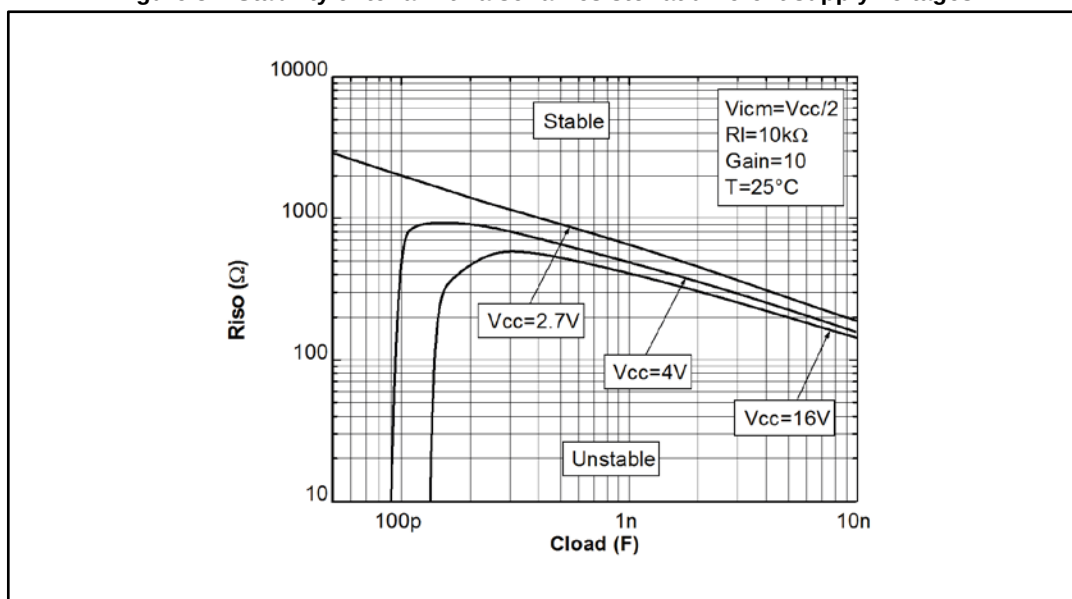
## 4.8 Capacitive load

Driving large capacitive loads can cause stability problems. Increasing the load capacitance produces gain peaking in the frequency response, with overshoot and ringing in the step response. It is usually considered that with a gain peaking higher than 2.3 dB an op amp might become unstable.

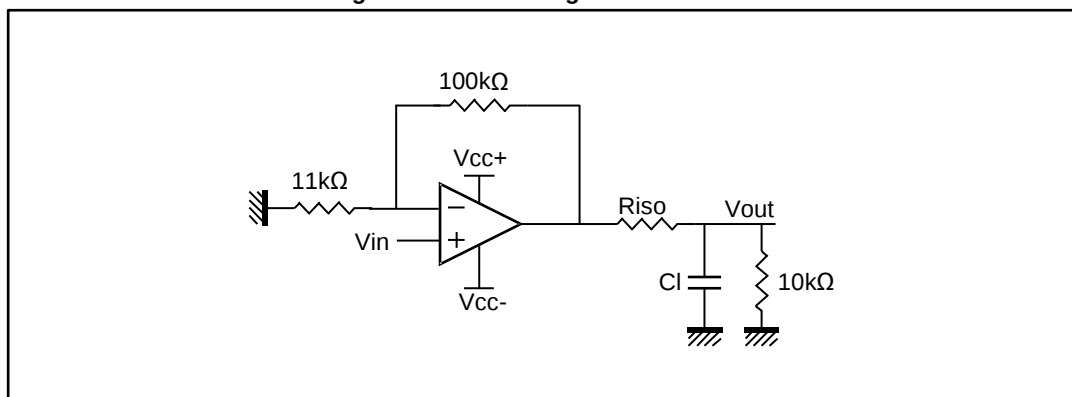
Generally, the unity gain configuration is the worst case for stability and the ability to drive large capacitive loads.

Figure 31 shows the serial resistor that must be added to the output, to make a system stable. Figure 32 shows the test configuration using an isolation resistor, Riso.

**Figure 31: Stability criteria with a serial resistor at different supply voltages**



**Figure 32: Test configuration for Riso**



## 4.9 PCB layout recommendations

Particular attention must be paid to the layout of the PCB, tracks connected to the amplifier, load, and power supply. The power and ground traces are critical as they must provide adequate energy and grounding for all circuits. The best practice is to use short and wide PCB traces to minimize voltage drops and parasitic inductance.

In addition, to minimize parasitic impedance over the entire surface, a multi-via technique that connects the bottom and top layer ground planes together in many locations is often used.

The copper traces that connect the output pins to the load and supply pins should be as wide as possible to minimize trace resistance.

## 4.10 Optimized application recommendation

It is recommended to place a 22 nF capacitor as close as possible to the supply pin. A good decoupling will help to reduce electromagnetic interference impact.

## 5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

## 5.1 MiniSO8 package information

Figure 33: MiniSO8 package outline

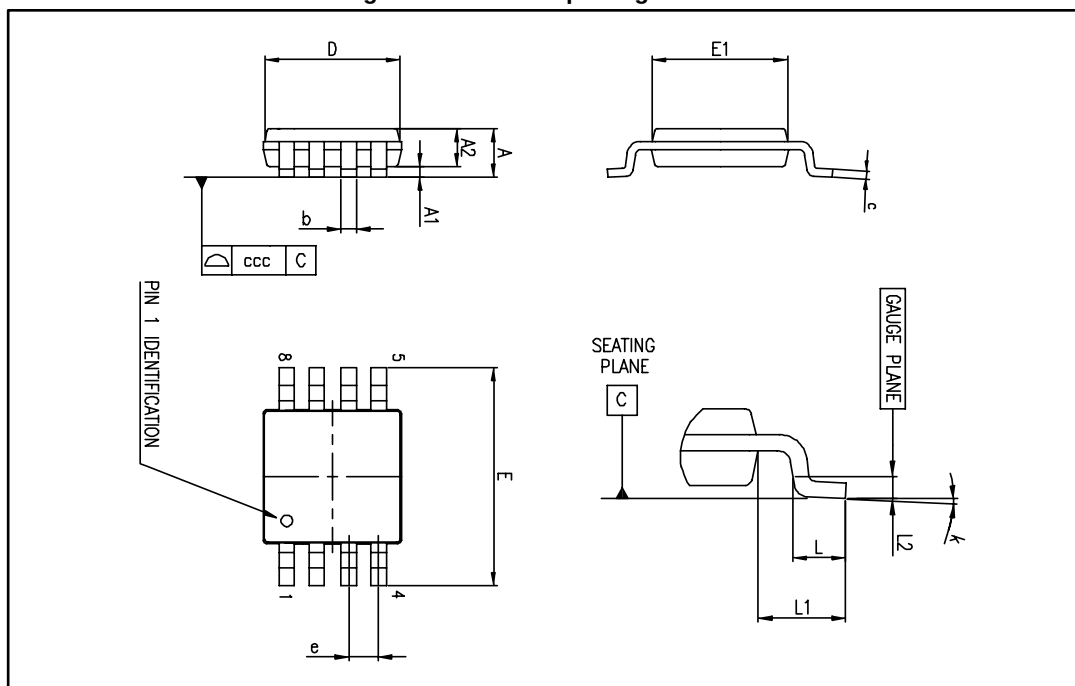


Table 6: MiniSO8 package mechanical data

| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    |             |      | 1.1  |        |       | 0.043 |
| A1   | 0           |      | 0.15 | 0      |       | 0.006 |
| A2   | 0.75        | 0.85 | 0.95 | 0.030  | 0.033 | 0.037 |
| b    | 0.22        |      | 0.40 | 0.009  |       | 0.016 |
| c    | 0.08        |      | 0.23 | 0.003  |       | 0.009 |
| D    | 2.80        | 3.00 | 3.20 | 0.11   | 0.118 | 0.126 |
| E    | 4.65        | 4.90 | 5.15 | 0.183  | 0.193 | 0.203 |
| E1   | 2.80        | 3.00 | 3.10 | 0.11   | 0.118 | 0.122 |
| e    |             | 0.65 |      |        | 0.026 |       |
| L    | 0.40        | 0.60 | 0.80 | 0.016  | 0.024 | 0.031 |
| L1   |             | 0.95 |      |        | 0.037 |       |
| L2   |             | 0.25 |      |        | 0.010 |       |
| k    | 0°          |      | 8°   | 0°     |       | 8°    |
| ccc  |             |      | 0.10 |        |       | 0.004 |

## 5.2 SO8 package information

Figure 34: SO8 package outline

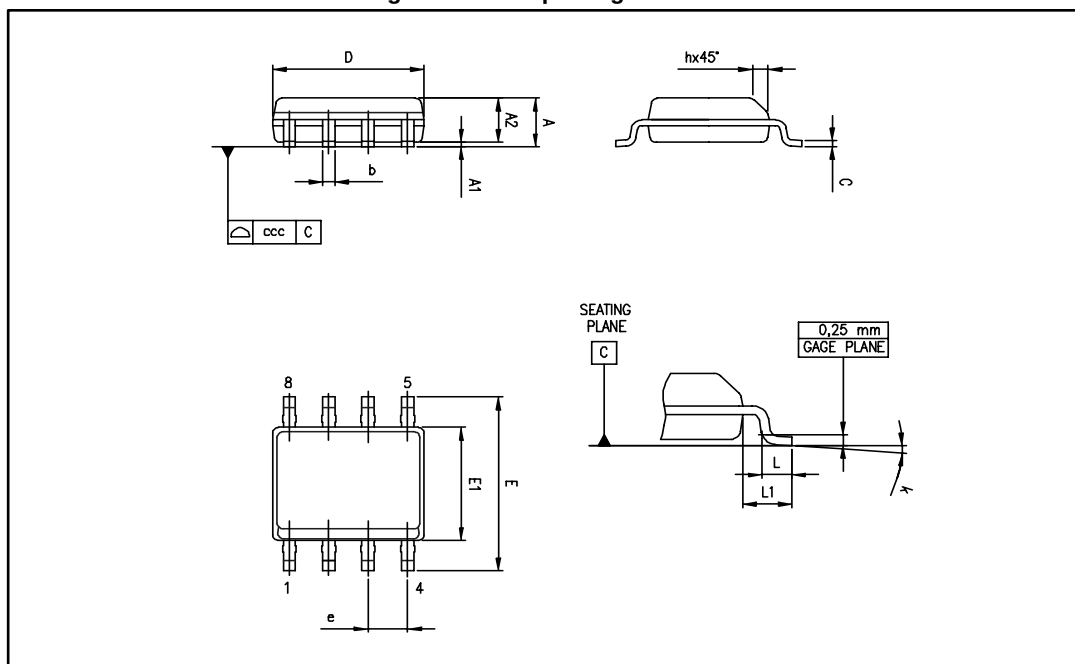


Table 7: SO8 package mechanical data

| Ref. | Dimensions  |      |      |        |       |       |
|------|-------------|------|------|--------|-------|-------|
|      | Millimeters |      |      | Inches |       |       |
|      | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A    |             |      | 1.75 |        |       | 0.069 |
| A1   | 0.10        |      | 0.25 | 0.004  |       | 0.010 |
| A2   | 1.25        |      |      | 0.049  |       |       |
| b    | 0.28        |      | 0.48 | 0.011  |       | 0.019 |
| c    | 0.17        |      | 0.23 | 0.007  |       | 0.010 |
| D    | 4.80        | 4.90 | 5.00 | 0.189  | 0.193 | 0.197 |
| E    | 5.80        | 6.00 | 6.20 | 0.228  | 0.236 | 0.244 |
| E1   | 3.80        | 3.90 | 4.00 | 0.150  | 0.154 | 0.157 |
| e    |             | 1.27 |      |        | 0.050 |       |
| h    | 0.25        |      | 0.50 | 0.010  |       | 0.020 |
| L    | 0.40        |      | 1.27 | 0.016  |       | 0.050 |
| L1   |             | 1.04 |      |        | 0.040 |       |
| k    | 1°          |      | 8°   | 1°     |       | 8°    |
| ccc  |             |      | 0.10 |        |       | 0.004 |

## 6 Ordering information

Table 8: Order codes

| Order code                 | Temperature range                   | Package | Packaging     | Marking  |
|----------------------------|-------------------------------------|---------|---------------|----------|
| TSX7192IDT                 | -40 to +125 °C                      | SO8     | Tape and reel | TSX7192  |
| TSX7192IST                 |                                     | MiniSO8 |               | K210     |
| TSX7192IYDT <sup>(1)</sup> | -40 to +125 °C,<br>automotive grade | SO8     |               | TSX7192Y |
| TSX7192IYST <sup>(1)</sup> |                                     | MiniSO8 |               | K213     |

**Notes:**

<sup>(1)</sup> Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent are on-going.

## 7 Revision history

**Table 9: Document revision history**

| Date        | Revision | Changes         |
|-------------|----------|-----------------|
| 06-Mar-2015 | 1        | Initial release |

**IMPORTANT NOTICE – PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2015 STMicroelectronics – All rights reserved